











TCAN1044-Q1, TCAN1044V-Q1

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TCAN1044-Q1 Automotive Fault-Protected CAN FD Transceiver

1 Features

- AEC-Q100: Qualified for automotive applications
 - Temperature grade 1: –40°C to 125°C T_A
- Meets the requirements of ISO 11898-2:2016 and ISO 11898-5:2007 physical layer standards
- Support of classical CAN and optimized CAN FD performance at 2, 5, and 8 Mbps
 - Short and symmetrical propagation delays and fast loop times for enhanced timing margin
 - Higher data rates in loaded CAN networks
- IO voltage range supports 1.7 V to 5.5 V
 - Support for 1.8-V, 2.5-V, 3.3-V, and 5-V applications
- Receiver common mode input voltage: ±12 V
- Protection features:
 - Bus fault protection: ±58 V
 - Under-voltage protection
 - TXD-dominant time-out (DTO)
 - Data rates down to 9.2 kbps
 - Thermal-shutdown protection (TSD)
- Operating modes:
 - Normal mode
 - Low power standby mode supporting remote wake-up request
- Optimized behavior when unpowered
 - Bus and logic pins are high impedance (no load to operating bus or application)
 - Hot-plug capable: power up/down glitch free operation on bus and RXD output
- Junction temperatures from: –40°C to 150°C
- Available in SOIC (8), SOT23 (8) packages (2.9 mm x 1.60 mm) and leadless VSON (8) packages (3.0 mm x 3.0 mm) with improved automated optical inspection (AOI) capability

2 Applications

- Automotive and Transportation
 - Body control modules
 - Automotive gateway
 - Advanced driver assistance system (ADAS)
 - Infotainment

3 Description

The TCAN1044-Q1 is a high speed controller area network (CAN) transceiver that meets the physical layer requirements of the ISO 11898-2:2016 high-speed CAN specification.

TCAN1044-Q1 transceiver supports classical CAN and CAN FD networks up to 8 megabits per second (Mbps). The TCAN1044-Q1 includes internal logic level translation via the V_{IO} terminal to allow for interfacing the transceiver IOs directly to 1.8-V, 2.5-V, 3.3-V, or 5-V logic IOs. The transceiver has a low-power standby mode which supports remote wake-up via the ISO 11898-2:2016 defined wake-up pattern (WUP). The TCAN1044-Q1 transceiver also includes many protection and features including thermal-shutdown diagnostic (TSD), TXD-dominant time-out (DTO), supply undervoltage detection, and bus fault protection up to ±58 V.

Device Information(1)

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TCAN1044x-Q1	SOT (8)	2.90 mm x 1.60 mm
	VSON (8)	3.00 mm x 3.00 mm
	SOIC (8)	4.90 mm x 3.91 mm

 For all available packages, see the orderable addendum at the end of the data sheet.

Simplified Block Diagram

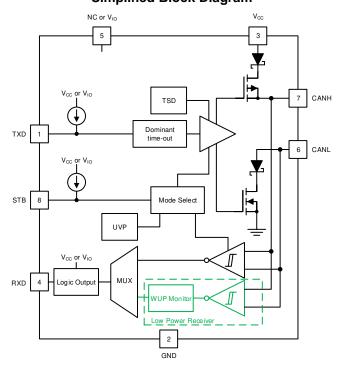




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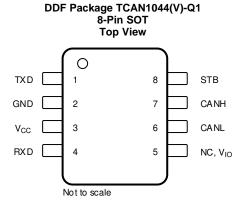
4 Revision History

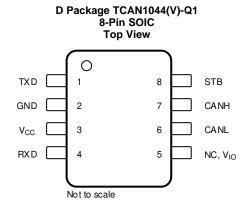
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

C	changes from Original (August 2019) to Revision A	Page
•	First public release of the data sheet	1
•	Added SAE j2962-2 ESD	4
•	Changed foortnote to Tested according to IEC 62228-3:2019 CAN Transceivers, Section 6.3; standard pulses parameters defined in ISO 7637-2 (2011)	4

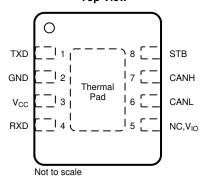


5 Pin Configuration and Functions





DRB Package TCAN1044(V)-Q1 8-Pin VSON Top View



Pin Functions

	Pins	Tyma	Description
Name	No.	Type	Description
TXD	1	Digital Input	CAN transmit data input
GND	2	GND	Ground connection
V _{CC}	3	Supply	5-V supply voltage
RXD	4	Digital Output	CAN receive data output, tri-state when powered off
NC	- 5	_	No Connect (not internally connected); Devices without V _{IO}
V_{IO}	5	Supply	IO supply voltage
CANL	6	Bus IO	Low-level CAN bus input/output line
CANH	7	Bus IO	High-level CAN bus input/output line
STB	8	Digital Input	Standby input for mode control, integrated pull up
Thermal Pad	(VSON only)	_	Electrically connected to GND, connect the thermal pad to the printed circuit board (PCB) ground plane for thermal relief



6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)(2)

		MIN	MAX	UNIT
V _{CC}	Supply voltage	-0.3	6	V
V _{IO}	Supply voltage IO level shifter	-0.3	6	V
V _{BUS}	CAN Bus IO voltage CANH and CANL	-58	58	V
V_{DIFF}	Max differential voltage between CANH and CANL	-45	45	V
V _{Logic_Input}	Logic input terminal voltage	-0.3	6	V
V _{RXD}	RXD output terminal voltage range	-0.3	6	V
I _{O(RXD)}	RXD output current	-8	8	mA
T _J	Operating virtual junction temperature range	-40	150	°C
T _{STG}	Storage temperature	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

V _{ESD}		Human-body model (HBM), per AEC Q100-002 ⁽¹⁾	HBM classification level 3A for all pins	±3000	V
	Electrostatic discharge	, , , , , , , , , , , , , , , , , , , ,	HBM classififation level 3B for global pins CANH & CANL	±10000	٧
		Charged-device model (CDM), per AEC Q100-011 CDM classification level C5 for all pins		±750	V

⁽¹⁾ AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

6.3 ESD Ratings

				VALUE	UNIT
V	System Level Electro-Static Discharge	CAN bus terminals (CANH, CANL) to GND	SAE J2962-2 per ISO 10650 Powered Contact Discharge	±8000	V
V _{ESD}	(ESD) ⁽¹⁾	CAN bus terminals (CANTI, CANE) to GND	SAE J2962-2 per ISO 10650 Powered Air Discharge	±15000	V
	ISO 7637 ISO Pulse Transients (2)	CANILLY ASSESSED (CANILL CANILL)	Pulse 1	-100	V
			Pulse 2a	75	V
V_{Tran}	150 7637 ISO Pulse Transients	CAN bus terminals (CANH, CANL)	Pulse 3a	-150	V
			Pulse 3b	100	V
	ISO 7637 Slow transients pulse ⁽³⁾	CAN bus terminals (CANH, CANL) to GND	DCC slow transient pulse	±85	V

Results given here are specific to the SAE J2962-2 Communication Transceivers Qualification Requirements - CAN. Testing performed by OEM approved independent 3rd party, EMC report available upon request.

6.4 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	4.5	5	5.5	V
V_{IO}	Supply voltage for IO level shifter	1.7		5.5	V
I _{OH(RXD)}	RXD terminal high level output current	-2			mA
I _{OL(RXD)}	RXD terminal low level output current			2	mA
T _A	Operating ambient temperature	-40		125	°C

⁽²⁾ All voltage values, except differential IO bus voltages, are with respect to ground terminal.

⁽²⁾ Tested according to IEC 62228-3:2019 CAN Transcievers, Section 6.3; standard pulses parameters defined in ISO 7637-2 (2011)

⁽³⁾ Tested according to ISO 7637-3 (2017); Electrical transient transmission by capacitive and inductive coupling via lines other than supply lines



6.5 Thermal Characteristics

	THERMAL METRIC ⁽¹⁾		UNIT		
I DERMAL METRIC		D (SOIC)	DDF (SOT)	DRB (VSON)	UNIT
$R_{\Theta JA}$	Junction-to-ambient thermal resistance	128.1	119.9	49.9	°C/W
$R_{\Theta JC(top)}$	Junction-to-case (top) thermal resistance	68.3	61.8	58.2	°C/W
$R_{\Theta JB}$	Junction-to-board thermal resistance	71.6	39.7	23.9	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	19.7	2.1	1.7	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	70.8	39.5	23.8	°C/W
R _{OJC(bot)}	Junction-to-case (bottom) thermal resistance	-	-	6.4	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application

6.6 Supply Characteristics

Over recommended operating conditions with T_A = -40°C to 125°C (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
		Dominant	See Figure 5,TXD = 0 V, STB = 0 V, $R_L = 60 \Omega$, $C_L = open$		45	70	mA
	Supply current normal	Dominant	See Figure 5, TXD = 0 V, STB = 0 V, R _L = 50 Ω , C _L = open		49	80	mA
I _{cc}	mode	Recessive	See Figure 5, TXD = V_{CC} , STB = 0 V, R_L = 50 Ω , C_L = open, RCM = open		4.5	7.5	mA
		Dominant with bus fault	See Figure 5, TXD = 0 V, STB = 0 V, CANH = CANL = ± 25 V, R _L = open, C _L = open			130	mA
I _{cc}	Supply current standby mode Devices with V _{IO}		$\begin{aligned} TXD &= STB = V_{IO} \\ R_L &= 50 \ \Omega, \ C_L = open \\ See \ Figure \ 5 \end{aligned}$		0.2	1	μΑ
I _{cc}	Supply current standby mode Devices without V _{IO}		$\begin{aligned} TXD &= STB = V_{CC} \\ R_L &= 50 \ \Omega, \ C_L = open \\ See \ Figure \ 5 \end{aligned}$			14.5	μΑ
I _{IO}	IO supply current normal mode	Dominant	TXD = 0 V, STB= 0 V RXD floating		125	300	μΑ
I _{IO}	IO supply current normal mode	Recessive	TXD = 0 V, STB = 0 V RXD floating		25	48	μA
I _{IO}	IO supply current standby r	node	TXD = 0 V, STB = V _{IO} RXD floating		8.5	13.5	μA
UV _{VCC}	Rising under voltage detection on V _{CC} for protected mode			4.2	4.4	V	
UV _{VCC}	Falling under voltage detection on V _{CC} for protected mode		tected mode	3.5	4	4.25	V
UV _{VIO}	Rising under voltage detection on V _{IO} (Devices with V _{IO})				1.56	1.65	V
UV_{VIO}	Falling under voltage detec	tion on V _{IO} (Device	s with V _{IO})	1.4	1.51	1.59	V

6.7 Dissipation Ratings

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
		$\begin{array}{l} V_{CC} = 5 \text{ V, } V_{IO} = 1.8 \text{ V, } T_{J} = 27^{\circ}\text{C, } R_{L} = 60\Omega, \\ \text{TXD input} = 250 \text{ kHz } 50\% \text{ duty cycle} \\ \text{squarewave, } C_{L_RXD} = 15 \text{ pF} \end{array}$		110		mW
		$\begin{aligned} & V_{CC} = 5 \; V, V_{IO} = 3.3 \; V, T_{I} = 27^{\circ} C, \; R_{L} = 60\Omega, \\ & TXD \; input = 250 \; kHz \; 50\% \; duty \; cycle \\ & squarewave, \; C_{L_{RXD}} = 15 \; pF \end{aligned}$		110		mW
P _D	Average power dissipation Normal mode	$ \begin{vmatrix} V_{\text{CC}} = 5 \text{ V, } V_{\text{IO}} = 5 \text{ V, } T_{\text{J}} = 27^{\circ}\text{C, } R_{\text{L}} = 60\Omega, \text{ TXD} \\ \text{input} = 250 \text{ kHz } 50\% \text{ duty cycle squarewave,} \\ C_{\text{L}_{-\text{RXD}}} = 15 \text{ pF} \\ \end{vmatrix} $		110		mW
		V_{CC} = 5.5 V, V_{IO} = 1.8 V, T_A = 125°C, R_L = 60 Ω , TXD input = 2.5 MHz 50% duty cycle squarewave, C_{L_RXD} = 15 pF		120		mW
		$\begin{array}{l} V_{CC} = 5.5 \text{ V}, V_{IO} = 3.3 \text{ V}, T_A = 125^{\circ}\text{C}, R_L = \\ 60\Omega, \text{TXD input} = 2.5 \text{ MHz} 50\% \text{ duty cycle} \\ \text{squarewave}, C_{L_RXD} = 15 \text{ pF} \end{array}$		120		mW
P _D	Average power dissipation Normal mode	$\begin{array}{l} V_{CC}=5.5~V,~V_{IO}=5~V,~T_{A}=125^{\circ}C,~R_{L}=60\Omega,\\ TXD~input=2.5~MHz~50\%~duty~cycle\\ squarewave,~C_{L_RXD}=15~pF \end{array}$		120		mW

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Dissipation Ratings (continued)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
T _{TSD}	Thermal shutdown temperature			192		5
T _{TSD_HYS}	Thermal shutdown hysteresis			10		C

6.8 Electrical Characteristics

			-40°C to 125°C (unless otherwise note		TVD	MAY	LINUT
	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
Driver Elect	rical Characteristics						
V _{O(DOM)}	Dominant output voltage	CANH	See Figure 6 and Figure 14, TXD = 0 V, STB = 0 V, 50 $\Omega \le R_L \le 65 \Omega$, $C_L = open$,	2.75		4.5	V
VO(DOM)	normal mode	CANL	R _{CM} = open	0.5		2.25	V
V _{O(REC)}	Recessive output voltage normal mode	CANH and CANL	See Figure 6 and Figure 14, TXD = V_{IO} , STB = 0 V, R_L = open (no load), R_{CM} = open	2	0.5 V _{CC}	3	V
V _{SYM}	Driver symmetry (V _{O(CANL)})/V _{CC}		See Figure 6 and Figure 18, STB = 0 V, R_L = 60 Ω , C_{SPLIT} = 4.7 nF, C_L = open, R_{CM} = open, TXD = 250 kHz, 1 MHz, 2.5 MHz	0.9		1.1	V/V
V _{SYM_DC}	DC output symmetry (V _{CC} - V _{O(CANH)} - V _{O(CANL)})		See Figure 6 and Figure 14, STB = 0 V, R_L = 60 Ω , C_L = open	-400		400	mV
	Differential output valtees		See Figure 6 and Figure 14, TXD = 0 V, STB = 0 V, 50 Ω ≤ R _L ≤ 65 Ω , C _L = open	1.5		3	V
$V_{OD(DOM)}$	Differential output voltage normal mode Dominant	CANH - CANL	See Figure 6 and Figure 14, TXD = 0 V, STB = 0 V, 45 Ω ≤ R _L ≤ 70 Ω , C _L = open	1.4		3.3	٧
			See Figure 6 and Figure 14, TXD = 0 V, STB = 0 V, R_L = 2240 Ω , C_L = open	1.5		5	V
V _{OD(REC)}	Differential output voltage normal mode CANH - CAN	CANH - CANL	See Figure 6 and Figure 14, TXD = V_{IO} , STB = 0 V, R_L = 60 Ω , C_L = open	-120		12	mV
*OD(REC)	Recessive	0/4417 0/442	See Figure 6 and Figure 14, TXD = V_{IO} , STB = 0 V, R_L = open, C_L = open	– 50		50	mV
V _{O(STB)} Bus output voltage	CANH	0 5 0 15 11 075 11 5	-0.1		0.1	V	
	standby mode	CANL	See Figure 6 and Figure 14, STB = V_{IO} , R_L = open (no load), R_{CM} = open	-0.1		0.1	V
	Starraby mode	CANH - CANL	apan (na nada), nagar	-0.2		0.2	V
, Short-circuit steady-state	$V_{(C)}$ Short-circuit steady-state output current, $V_{(C)}$	See Figure 11 and Figure 14, STB = 0 V, V _(CANH) = -15 V to 40 V, CANL = open, TXD = 0 V	-115			mA	
los(ss_DOM) dominant, normal mode			See Figure 11 and Figure 14, STB = 0 V, $V_{(CAN_L)}$ = -15 V to 40 V, CANH = open, TXD = 0 V			115	mA
I _{OS(SS_REC)}	Short-circuit steady-state output current, recessive, normal mode		See Figure 11 and Figure 14, STB = 0 V, $-27 \text{ V} \le \text{V}_{BUS} \le 32 \text{ V}$, Where $\text{V}_{BUS} = \text{CANH} = \text{CANL}$, TXD = V_{IO}	- 5		5	mA
Receiver Ele	ectrical Characteristics		12				
V _{IT}	Input threshold voltage norr	mal mode	See Figure 7, Table 1, and Table 7 STB = 0 V, -12 V ≤ V _{CM} ≤ 12 V	500		900	mV
V _{IT(STB)}	Input threshold standby mo	de	See Figure 7, Table 1, and Table 7 STB = V_{IO} , -12 V $\leq V_{CM} \leq$ 12 V	400		1150	mV
V_{DOM}	Normal mode dominant stat voltage range	te differential input	See Figure 7, Table 1, and Table 7 STB = 0 V, -12 V ≤ V _{CM} ≤ 12 V	0.9		9	V
V_{REC}	Normal mode recessive sta voltage range	te differential input	See Figure 7, Table 1, and Table 7 STB = 0 V, -12 V ≤ V _{CM} ≤ 12 V	-4		0.5	٧
V _{DOM(STB)}	Standby mode dominant state differential input voltage range		See Figure 7, Table 1, and Table 7 STB = V_{IO} , -12 V $\leq V_{CM} \leq$ 12 V	1.15		9	٧
V _{REC(STB)}	Standby mode recessive stavoltage range	ate differential input	See Figure 7, Table 1, and Table 7 STB = V_{IO} , -12 V $\leq V_{CM} \leq$ 12 V	-4		0.4	٧
V _{HYS}	Hysteresis voltage for input mode	threshold normal	See Figure 7, Table 1, and Table 7 STB = 0 V, -12 V ≤ V _{CM} ≤ 12 V		100		mV
V _{CM}	Common mode range norm modes	al and standby	See Figure 7 and Table 7	-12		12	V
I _{LKG(IOFF)}	Unpowered bus input leaka	ge current	CANH = CANL = 5 V, V _{CC} = V _{IO} = GND			5	μΑ

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Electrical Characteristics (continued)

Over recomended operating conditions with $T_A = -40$ °C to 125°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
C _I Input capacitance to ground (CANH or CANL)		TVD (1)			20	pF
C _{ID}	Differential input capacitance	$-TXD = V_{IO}^{(1)}$			10	pF
R _{ID}	Differential input resistance	TVP (1)	40		90	kΩ
R _{IN}	Single ended input resistance (CANH or CANL)	$\begin{array}{l} - \text{TXD} = \text{V}_{\text{IO}}^{(1)} \\ \text{STB} = 0 \text{ V}, -12 \text{ V} \leq \text{V}_{\text{CM}} \leq 12 \text{ V} \end{array}$	20		45	kΩ
R _{IN(M)}	Input resistance matching [1 – (R _{IN(CANH)} / R _{IN(CANL)})] × 100 %	$V_{(CAN_H)} = V_{(CAN_L)} = 5 \text{ V}$	-1		1	%
TXD Termi	inal (CAN Transmit Data Input)		•			
V _{IH}	High-level input voltage	Devices without V _{IO}	0.7 V _{CC}			V
V_{IH}	High-level input voltage	Devices with V _{IO}	0.7 V _{IO}			V
V _{IL}	Low-level input voltage	Devices without V _{IO}			0.3 V _{CC}	V
V _{IL}	Low-level input voltage	Devices with V _{IO}			0.3 V _{IO}	V
I _{IH}	High-level input leakage current	$TXD = V_{CC} = V_{IO} = 5.5 \text{ V}$	-2.5	0	1	μA
I _{IL}	Low-level input leakage current	TXD = 0 V, V _{CC} = V _{IO} = 5.5 V	-200	-100	-20	μA
I _{LKG(OFF)}	Unpowered leakage current	$TXD = 5.5 \text{ V}, V_{CC} = V_{IO} = 0 \text{ V}$	-1	0	1	μA
Cı	Input Capacitance	$V_{IN} = 0.4 \times \sin(2 \times \pi \times 2 \times 10^6 \times t) + 2.5 \text{ V}$		5		pF
RXD Term	inal (CAN Receive Data Output)					I
V _{OH}	High-level input voltage	Devices without V _{IO} See Figure 7, I _O = -2 mA	0.8 V _{CC}			V
V _{OH}	High-level input voltage	Devices with V_{IO} See Figure 7, $I_{O} = -2$ mA	0.8 V _{IO}			V
V _{OL}	Low-level input voltage	Devices without V _{IO} See Figure 7, I _O = 2 mA			0.2 V _{CC}	V
V _{OL}	Low-level input voltage	Devices with V _{IO} See Figure 7, I _O = 2 mA			0.2 V _{IO}	V
I _{LKG(OFF)}	Unpowered leakage current	RXD = 5.5 V, V _{CC} = V _{IO} = 0 V	-1	0	1	μΑ
STB Termi	inal (Standby Mode Input)					
V _{IH}	High-level input voltage	Devices without V _{IO}	0.7 V _{CC}			V
V_{IH}	High-level input voltage	Devices with V _{IO}	0.7 V _{IO}			V
V _{IL}	Low-level input voltage	Devices without V _{IO}			0.3 V _{CC}	V
V _{IL}	Low-level input voltage	Devices with V _{IO}			0.3 V _{IO}	V
I _{IH}	High-level input leakage current STB	$V_{CC} = V_{IO} = STB = 5.5 \text{ V}$	-2		2	μA
I _{IL}	Low-level input leakage current STB	V _{CC} = V _{IO} = 5.5 V, STB = 0 V	-20		-2	μA
I _{LKG(OFF)}	Unpowered leakage current	STB = 5.5V, V _{CC} = V _{IO} = 0 V	-1	0	1	μΑ

⁽¹⁾ $V_{IO} = V_{CC}$ in non-V variants of device

6.9 Switching Characteristics

Over recomended operating conditions with $T_A = -40$ °C to 125°C (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Device Switching Characteristics							
t _{PROP(LOOP1)}	Total loop delay, driver input (TXD) to receiver	See Figure 8, normal mode, V_{IO} = 2.8 V to 5.5 V, R_L = 60 Ω , C_L = 100 pF, $C_{L(RXD)}$ = 15 pF		125	210	ns	
	output (RXD), recessive to dominant	See Figure 8, normal mode, V_{IO} = 1.7 V, R_L = 60 Ω , C_L = 100 pF, $C_{L(RXD)}$ = 15 pF		165	255	ns	
t _{PROP(LOOP2)}	Total loop delay, driver input (TXD) to receiver output (RXD), dominant to recessive	See Figure 8, normal mode, V_{IO} = 2.8 V to 5.5 V, R_L = 60 Ω , C_L = 100 pF, $C_{L(RXD)}$ = 15 pF		150	210	ns	
		See Figure 8, normal mode, V_{IO} = 1.7 V, R_L = 60 Ω , C_L = 100 pF, $C_{L(RXD)}$ = 15 pF		180	255	ns	
t _{MODE}	Mode change time, from normal to standby or from standby to normal	See Figure 9			20	μs	
t _{WK_FILTER}	Filter time for a valid wake-up pattern	See Figure 16	0.5		1.8	μs	



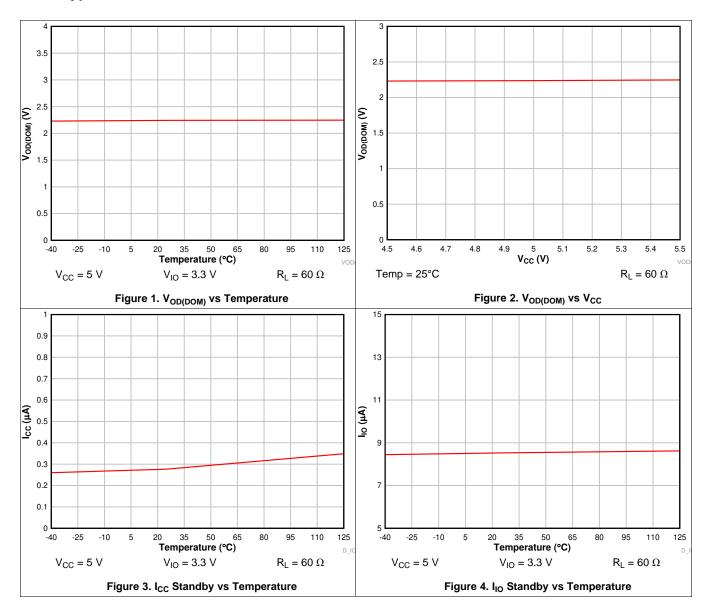
Switching Characteristics (continued)

Over recomended operating conditions with $T_A = -40$ °C to 125°C (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{WK_TIMEOUT}	Bus wake-up timeout value	See Figure 16	0.8		6	ms
Driver Switchin	ng Characteristics					
t _{pHR}	Propagation delay time, high TXD to driver recessive (dominant to recessive)			80		ns
t _{pLD}	Propagation delay time, low TXD to driver dominant (recessive to dominant)	See Figure 6, STB = 0 V, R_L = 60 Ω , C_L		70		ns
t _{sk(p)}	Pulse skew (tpHR - tpLD)	= 100 pF, R _{CM} = open		20		ns
t _R	Differential output signal rise time			30		ns
t _F	Differential output signal fall time			50		ns
t _{TXD_DTO}	Dominant timeout	See Figure 10, $R_L = 60 \Omega$, $C_L = 100 pF$, $STB = 0 V$	1.2		4.0	ms
Receiver Switch	hing Characteristics					
t _{pRH}	Propagation delay time, bus recessive input to high output (dominant to recessive)			90		ns
t _{pDL}	Propagation delay time, bus dominant input to low output (recessive to dominant)	See Figure 7 STB = 0 V,		65		ns
t _R	RXD output signal rise time	$C_{L(RXD)} = 15 \text{ pF}$		10		ns
t _F	RXD output signal fall time			10		ns
FD Timing Cha	racteristics					
t _{BIT(BUS)}	Bit time on CAN bus output pins with $t_{BIT(TXD)}$ = 500 ns		450		530	ns
t _{BIT(BUS)}	Bit time on CAN bus output pins with $t_{BIT(TXD)}$ = 200 ns	See Figure 8, STB = 0 V, R_L = 60 Ω , C_L = 100 pF, $C_{L(RXD)}$ = 15 pF	155		210	ns
t _{BIT(RXD)}	Bit time on RXD output pins with $t_{BIT(TXD)} = 500 \text{ ns}$	STB = 0 V	400		550	ns
t _{BIT(RXD)}	Bit time on RXD output pins with $t_{BIT(TXD)} = 200 \text{ ns}$		120		220	ns
t _{REC}	Receiver timing symmetry with t _{BIT(TXD)} = 500 ns	$R_L = 60 \Omega$, $C_L = 100 pF$, $C_{L(RXD)} = 15 pF$ -50		20	ns	
t _{REC}	Receiver timing symmetry with t _{BIT(TXD)} = 200 ns	$\Delta t_{REC} = t_{BIT(RXD)} - t_{BIT(BUS)}$	-45		15	ns



6.10 Typical Characteristics





7 Parameter Measurement Information

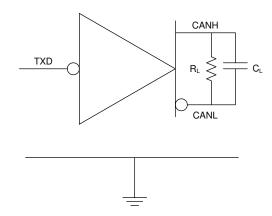


Figure 5. I_{CC} Test Circuit

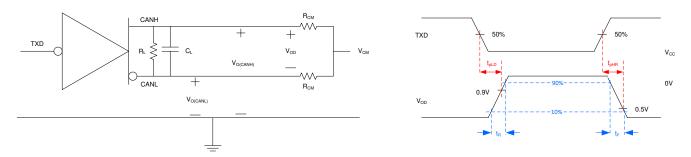


Figure 6. Driver Test Circuit and Measurement

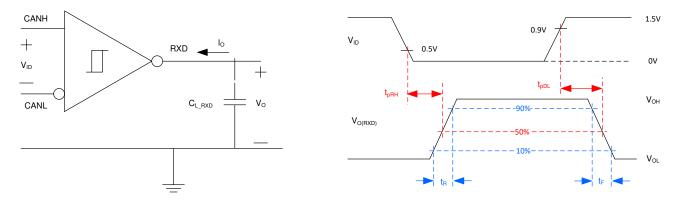


Figure 7. Receiver Test Circuit and Measurement



Parameter Measurement Information (continued) Table 1. Receiver Differential Input Voltage Threshold Test (See Figure 7)

Input			Out	tput	
V_{CANH}	V _{CANL}	V _{ID}	RXD		
-11.5 V	-12.5 V	1000 mV	L		
12.5 V	11.5 V	1000 mV		V	
-8.55 V	-9.45 V	900 mV		V _{OL}	
9.45 V	8.55 V	900 mV			
-8.25 V	-9.25 V	500 mV			
9.25 V	8.25 V	500 mV			
-11.8 V	-12.2 V	400 mV	н	V _{OH}	
12.2 V	11.8 V	400 mV			
Open	Open	Х			

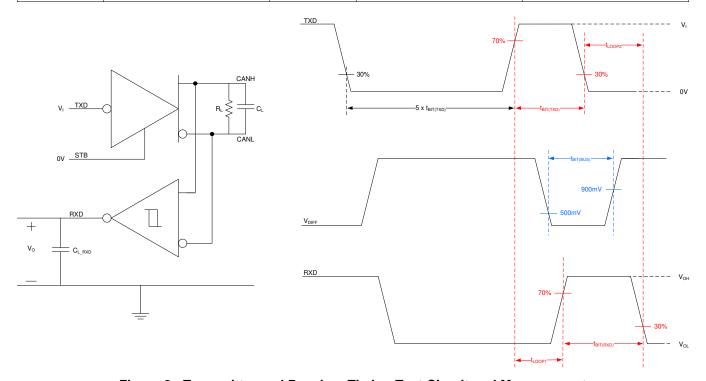


Figure 8. Transmitter and Receiver Timing Test Circuit and Measurement



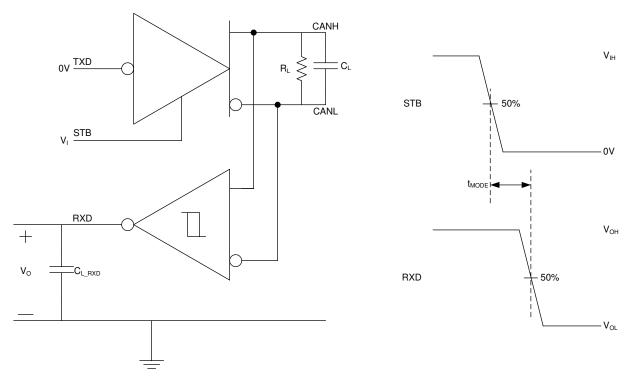


Figure 9. t_{MODE} Test Circuit and Measurement

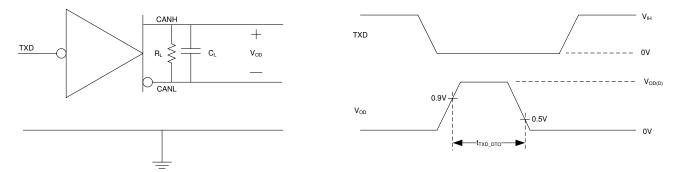


Figure 10. TXD Dominant Timeout Test Circuit and Measurement



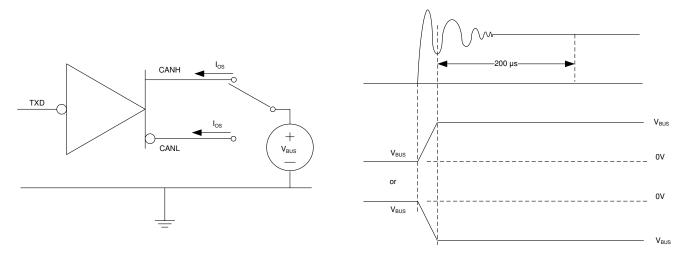


Figure 11. Driver Short-Circuit Current Test and Measurement



8 Detailed Description

8.1 Overview

The TCAN1044-Q1 meets or exceeds the specifications of the ISO 11898-2:2016 high speed CAN (Controller Area Network) physical layer standard. The device has been certified to the requirements of ISO 11898-2:2016 and ISO 11898-5:2007 physical layer requirements according to the GIFT/ICT high speed CAN test specification. The transceiver provides a number of different protection features making it ideal for the stringent automotive system requirements while also supporting CAN FD data rates up to 8 Mbps.

The TCAN1044-Q1 conforms to the following CAN standards:

- CAN Transceiver Physical Layer Standards
 - ISO 11898-2:2016 High speed medium access unit
 - ISO 11898-5:2007 High speed medium access unit with low-power mode
 - SAE J2284-1: High Speed CAN (HSC) for Vehicle Applications at 125 kbps
 - SAE J2284-2: High Speed CAN (HSC) for Vehicle Applications at 250 kbps
 - SAE J2284-3: High Speed CAN (HSC) for Vehicle Applications at 500 kbps
 - SAE J2284-4: High-Speed CAN (HSC) for Vehicle Applications at 500 kbps with CAN FD Data at 2 Mbps
 - SAE J2284-5: High-Speed CAN (HSC) for Vehicle Applications at 500 kbps with CAN FD Data at 5 Mbps
 - ARINC 825-4 General Standardization of CAN (Controller Area Network) Bus Protocol For Airborne Use
 - VeLIO (Vehicle LAN Interoperability and Optimization) CAN and CAN-FD Transceiver Requirements
- EMC requirements:
 - SAE J2962-2 Communication Transceivers Qualification Requirements CAN
- Conformance Test requirements:
 - ISO 16845-2 Road vehicles Controller area network (CAN) conformance test plan Part 2: High-speed medium access unit conformance test plan



8.2 Functional Block Diagram

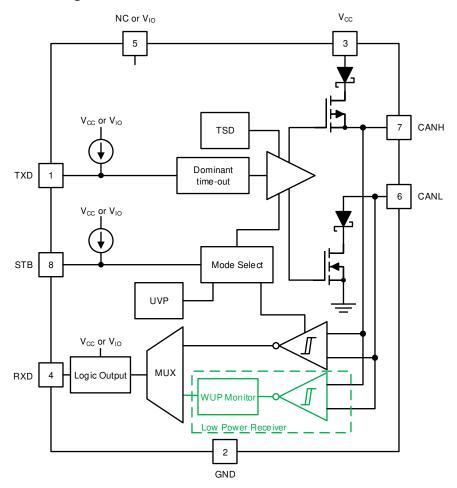


Figure 12. Block Diagram



8.3 Feature Description

8.3.1 Pin Description

8.3.1.1 TXD

TXD is the logic-level signal, referenced to either V_{CC} or V_{IO} from a CAN controller to the device.

8.3.1.2 GND

GND is the ground pin of the transceiver, it must be connected to the PCB ground.

8.3.1.3 V_{CC}

V_{CC} provides the 5-V nominal power supply to the CAN transceiver.

8.3.1.4 RXD

RXD is the logic-level signal, referenced to either V_{CC} or V_{IO} , from the TCAN1044-Q1 to a CAN controller. This pin is only driven once V_{IO} is present.

When a wake event takes place RXD is driven low.

8.3.1.5 V₁₀

The V_{IO} pin provides the digital IO voltage to match the CAN controller voltage thus avoiding the requirement for a level shifter. It supports voltages from 1.7 V to 5.5 V providing the widest range of controller support.

8.3.1.6 CANH and CANL

These are the CAN high and CAN low differential bus pins. These pins are connected to the CAN transceiver and the low-voltage WUP CAN receiver.

8.3.1.7 STB (Standby)

The STB pin is an input pin used for mode control of the transceiver. The STB pin can be supplied from either the system processor or from a static system voltage source. If normal mode is the only intended mode of operation than the STB pin can be tied directly to GND.

8.3.2 CAN Bus States

The CAN bus has two logical states during operation: recessive and dominant. See Figure 13 and Figure 14.

A dominant bus state occurs when the bus is driven differentially and corresponds to a logic low on the TXD and RXD pins. A recessive bus state occurs when the bus is biased to $V_{CC}/2$ via the high-resistance internal input resistors (R_{IN}) of the receiver and corresponds to a logic high on the TXD and RXD pins.

A dominant state overwrites the recessive state during arbitration. Multiple CAN nodes may be transmitting a dominant bit at the same time during arbitration, and in this case the differential voltage of the bus is greater than the differential voltage of a single driver.

The TCAN1044-Q1 transceiver implements a low-power standby (STB) mode which enables a third bus state where the bus pins are weakly biased to ground via the high resistance internal resistors of the receiver. See Figure 13 and Figure 14.



Feature Description (continued)

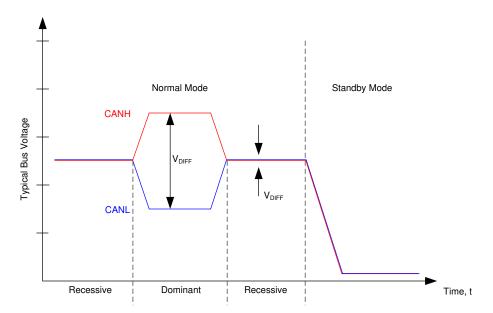
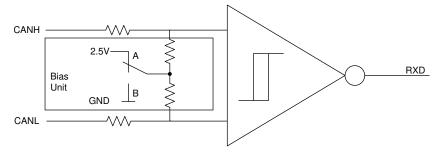


Figure 13. Bus States



- A. Normal Mode
- B. Standby Mode

Figure 14. Simplified Recessive Common Mode Bias Unit and Receiver

8.3.3 TXD Dominant Timeout (DTO)

During normal mode, the only mode where the CAN driver is active, the TXD DTO circuit prevents the local node from blocking network communication in the event of a hardware or software failure where TXD is held dominant longer than the timeout period t_{TXD_DTO} . The TXD DTO circuit is triggered by a falling edge on TXD. If no rising edge is seen before the timeout period of the circuit, t_{TXD_DTO} , the CAN driver is disabled. This frees the bus for communication between other nodes on the network. The CAN driver is reactivated when a recessive signal is seen on the TXD pin, thus clearing the dominant time out. The receiver remains active and biased to $V_{CC}/2$ and the RXD output reflects the activity on the CAN bus during the TXD DTO fault.

The minimum dominant TXD time allowed by the TXD DTO circuit limits the minimum possible transmitted data rate of the device. The CAN protocol allows a maximum of eleven successive dominant bits (on TXD) for the worst case, where five successive dominant bits are followed immediately by an error frame. The minimum transmitted data rate may be calculated using Equation 1.

Minimum Data Rate = 11 bits /
$$t_{TXD DTO}$$
 = 11 bits / 1.2 ms = 9.2 kbps (1)



Feature Description (continued)

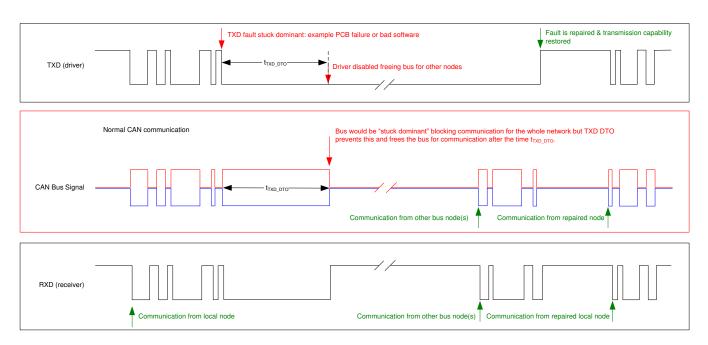


Figure 15. Example Timing Diagram for TXD Dominant Timeout

8.3.4 CAN Bus Short Circuit Current Limiting

The TCAN1044-Q1 has several protection features that limit the short circuit current when a CAN bus line is shorted. These include CAN driver current limiting in the dominant and recessive states and TXD dominant state timeout which prevents permanently having the higher short circuit current of a dominant state in case of a system fault. During CAN communication the bus switches between the dominant and recessive states, thus the short circuit current may be viewed as either the current during each bus state or as a DC average current. When selecting termination resistors or a common mode choke for the CAN design the average power rating, $I_{OS(AVG)}$, should be used. The percentage dominant is limited by the TXD DTO and the CAN protocol which has forced state changes and recessive bits due to bit stuffing, control fields, and interframe space. These ensure there is a minimum amount of recessive time on the bus even if the data field contains a high percentage of dominant bits.

The average short circuit current of the bus depends on the ratio of recessive to dominant bits and their respective short circuit currents. The average short circuit current may be calculated using Equation 2.

$$I_{OS(AVG)} = \% \text{ Transmit x } [(\% \text{ REC_Bits x } I_{OS(SS)_REC}) + (\% \text{ DOM_Bits x } I_{OS(SS)_DOM})] + [\% \text{ Receive x } I_{OS(SS)_REC}]$$
 (2)

Where:

- I_{OS(AVG)} is the average short circuit current
- % Transmit is the percentage the node is transmitting CAN messages
- % Receive is the percentage the node is receiving CAN messages
- % REC_Bits is the percentage of recessive bits in the transmitted CAN messages
- % DOM Bits is the percentage of dominant bits in the transmitted CAN messages
- I_{OS(SS)_REC} is the recessive steady state short circuit current
- I_{OS(SS)} DOM is the dominant steady state short circuit current

This short circuit current and the possible fault cases of the network should be taken into consideration when sizing the power supply used to generate the transceivers V_{CC} supply.

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Feature Description (continued)

8.3.5 Thermal Shutdown (TSD)

If the junction temperature of the TCAN1044-Q1 exceeds the thermal shutdown threshold, T_{TSD} , the device turns off the CAN driver circuitry and blocks the TXD to bus transmission path. The shutdown condition is cleared when the junction temperature of the device drops below T_{TSD} . The CAN bus pins are biased to $V_{CC}/2$ during a TSD fault and the receiver to RXD path remains operational. If the fault condition that caused the TSD fault is still present, the junction temperature may rise again and the device enters a TSD fault again. The TCAN1044-Q1 TSD circuit includes hysteresis which prevents the CAN driver output from oscillating during a TSD fault. If there is prolonged exposure to a TSD fault condition the device reliability could be affected.

8.3.6 Undervoltage Lockout

The supply pins, V_{CC} and V_{IO} , have undervoltage detection that places the device into a protected state. This protects the bus during an undervoltage event on either supply pin.

Table 2. Undervoltage Lockout - TCAN1044-Q1

V _{cc}	Device State	Bus	RXD Pin
> UV _{VCC}	Normal	Per TXD	Mirrors Bus
< UV _{VCC}	Protected	High Impedance	High Impedance

Table 3. Undervoltage Lockout - TCAN1044-Q1V

V _{CC}	V _{IO}	Device State	Bus	RXD Pin
> UV _{VCC}	> UV _{VIO}	Normal	Per TXD	Mirrors bus
. 111/	> UV _{VIO}	STB = V _{IO} : Standby mode	Biased to GND	V _{IO} : Remote wake request ⁽¹⁾
< UV _{VCC}		STB = GND: Protected mode	High impedance	Recessive
> UV _{VCC}	< UV _{VIO}	Protected	High impedance	High impedance
< UV _{VCC}	< UV _{VIO}	Protected	High impedance	High impedance

⁽¹⁾ See Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode

Once an undervoltage condition is cleared and the supply has returned to a valid level the TCAN1044-Q1 transitions to normal mode after the t_{MODE} time has expired. The host controller should not attempt to send or receive messages until the t_{MODE} time has expired.

8.3.7 Unpowered Device

The TCAN1044-Q1 is designed to be an ideal passive or no load to the CAN bus if the device is unpowered. The bus pins were designed to have low leakage currents when the device is unpowered, so they do not load the bus. This is critical if some nodes of the network are unpowered while the rest of the of network remains operational.

The logic pins also have low leakage currents when the device is unpowered, so they do not load other circuits which may remain powered.



8.3.8 Floating pins

The TCAN1044-Q1 has internal pull-ups on critical pins which place the device into known states if the pin floats. This internal bias should not be relied upon by design though, especially in noisy environments, but instead should be considered a failsafe protection feature.

When a CAN controller supporting open drain outputs are used an adequate external pull-up resistor must be used to ensure that the TXD output of the CAN controller maintains adequate bit timing to the input of the CAN transceiver. See Table 4 for details on pin bias conditions.

Table 4. Pin Bias

Pin	Pull-up or Pull-down	Comment
TXD	Pull-up	Weakly biases TXD towards recessive to prevent bus blockage or TXD DTO triggering
STB	Pull-up	Weakly biases STB towards low-power standby mode to prevent excessive system power

8.4 Device Functional Modes

8.4.1 Operating Modes

The TCAN1044-Q1 has two main operating modes; normal mode and standby mode. Operating mode selection is made by applying a high or low level to the STB pin on the TCAN1044 device.

Table 5. Operating Modes

STB	Device Mode	Driver	Receiver	RXD Pin
High	Low current standby mode with bus wake-up	Disabled	Low-power receiver and bus monitor enable	High (recessive) until valid WUP is received See section 8.3.3.1
Low	Normal Mode	Enabled	Enabled	Mirrors bus state

8.4.2 Normal Mode

This is the normal operating mode of the TCAN1044-Q1. The CAN driver and receiver are fully operational and CAN communication is bi-directional. The driver is translating a digital input on the TXD input to a differential output on the CANH and CANL bus pins. The receiver is translating the differential signal from CANH and CANL to a digital output on the RXD output.

8.4.3 Standby Mode

This is the low-power mode of the TCAN1044-Q1. The CAN driver and main receiver are switched off and bidirectional CAN communication is not possible. The low-power receiver and bus monitor circuits are enabled to allow for RXD wake-up requests via the CAN bus. A wake-up request is output to RXD as shown in Figure 16. The local CAN protocol controller should monitor RXD for transitions (high-to-low) and reactivate the device to normal mode by pulling the STB pin low. The CAN bus pins are weakly pulled to GND in this mode; see Figure 13 and Figure 14.

In standby mode, only the V_{IO} supply is required therefore the V_{CC} may be switched off for additional system level current savings.

8.4.3.1 Remote Wake Request via Wake-Up Pattern (WUP) in Standby Mode

The TCAN1044-Q1 supports a remote wake-up request that is used to indicate to the host controller that the bus is active and the node should return to normal operation.

The device uses the multiple filtered dominant wake-up pattern (WUP) from the ISO 11898-2:2016 standard to qualify bus activity. Once a valid WUP has been received, the wake request is indicated to the controller by a falling edge and low period corresponding to a filtered dominant on the RXD output of the TCAN1044-Q1.



The WUP consists of a filtered dominant pulse, followed by a filtered recessive pulse, and finally by a second filtered dominant pulse. The first filtered dominant initiates the WUP, and the bus monitor then waits on a filtered recessive; other bus traffic does not reset the bus monitor. Once a filtered recessive is received the bus monitor is waiting for a filtered dominant and again, other bus traffic does not reset the bus monitor. Immediately upon reception of the second filtered dominant the bus monitor recognizes the WUP and drives the RXD output low every time an additional filtered dominant signal is received from the bus.

For a dominant or recessive to be considered filtered, the bus must be in that state for more than the t_{WK_FILTER} time. Due to variability in t_{WK_FILTER} the following scenarios are applicable. Bus state times less than $t_{WK_FILTER(MIN)}$ are never detected as part of a WUP and thus no wake request is generated. Bus state times between $t_{WK_FILTER(MIN)}$ and $t_{WK_FILTER(MAX)}$ may be detected as part of a WUP and a wake-up request may be generated. Bus state times greater than $t_{WK_FILTER(MAX)}$ are always detected as part of a WUP, and thus a wake request is always generated. See Figure 16 for the timing diagram of the wake-up pattern.

The pattern and t_{WK_FILTER} time used for the WUP prevents noise and bus stuck dominant faults from causing false wake-up requests while allowing any valid message to initiate a wake-up request.

The ISO 11898-2:2016 standard has defined times for a short and long wake up filter time. The t_{WK_FILTER} timing for the device has been picked to be within the minimum and maximum values of both filter ranges. This timing has been chosen such that a single bit time at 500 kbps, or two back to back bit times at 1 Mbps triggers the filter in either bus state. Any CAN frame at 500 kbps or less would contain a valid WUP.

For an additional layer of robustness and to prevent false wake-ups, the device implement a wake-up timeout feature. For a remote wake-up event to successfully occur, the entire WUP must be received within the timeout value $t \le t_{WK_TIMEOUT}$. If not, the internal logic is reset and the transceiver remains in its current state without waking up. The full pattern must then be transmitted again, conforming to the constraints mentioned in this section. See Figure 16 for the timing diagram of the wake up pattern with wake timeout feature.

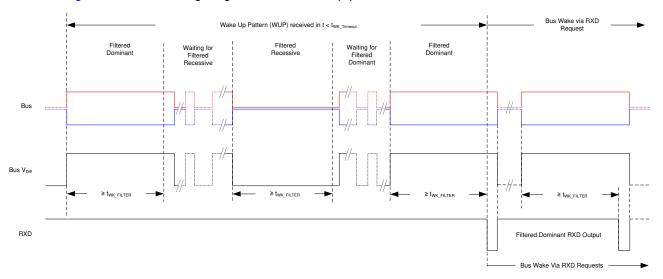


Figure 16. Wake-Up Pattern (WUP) with twk TIMEOUT



8.4.4 Driver and Receiver Function

The digital logic input and output levels for the TCAN1044-Q1 are CMOS levels with respect to either V_{CC} for 5 V systems or V_{IO} for compatibility with MCUs having 1.8 V, 2.5 V, 3.3 V, or 5 V systems.

Table 6. Driver Function Table

Davisa Mada	TXD Input ⁽¹⁾	Bus	Driven Bus State ⁽²⁾	
Device Mode	TAD input\	CANH	CANL	Driven bus State
Normal	Low	High	Low	Dominant
Normal	High or open	Hi-Z	Hi-Z	Biased recessive
Standby	X	Hi-Z	Hi-Z	Weak pull-down to ground

⁽¹⁾ X = irrelevant

Table 7. Receiver Function Table Normal and Standby Mode

Device Mode	CAN Differential Inputs V _{ID} = V _{CANH} - V _{CANL}	Bus State	RXD Pin
	V _{ID} ≥ 0.9 V	Dominant	Low
Normal	$0.5 \text{ V} < \text{V}_{\text{ID}} < 0.9 \text{ V}$	Undefined	Undefined
	V _{ID} ≤ 0.5 V	Recessive	High
	V _{ID} ≥ 1.15 V	Dominant	High
Standby	0.4 V < V _{ID} < 1.15 V	Undefined	Low if a remote wake event occurred
	V _{ID} ≤ 0.4 V	Recessive	See Figure 16
Any	Open (V _{ID} ≈ 0 V)	Open	High

⁽²⁾ For bus state and bias see Figure 13 and Figure 14



9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

9.2 Typical Application

The TCAN1044-Q1 transceiver can be used in applications with a host controller or FPGA that includes the link layer portion of the CAN protocol. Figure 17 shows a typical application configuration for 5 V controller applications. The bus termination is shown for illustrative purposes.

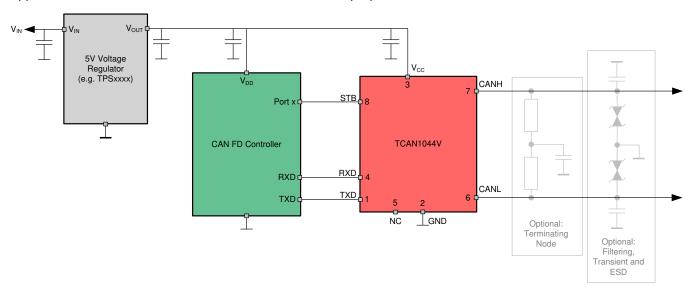


Figure 17. Transceiver Application Using 5 V IO Connections

9.2.1 Design Requirements

9.2.1.1 CAN Termination

Termination may be a single $120-\Omega$ resistor at each end of the bus, either on the cable or in a terminating node. If filtering and stabilization of the common mode voltage of the bus is desired then split termination may be used, see Figure 18. Split termination improves the electromagnetic emissions behavior of the network by filtering higher-frequency common-mode noise that may be present on the differential signal lines.



Typical Application (continued)

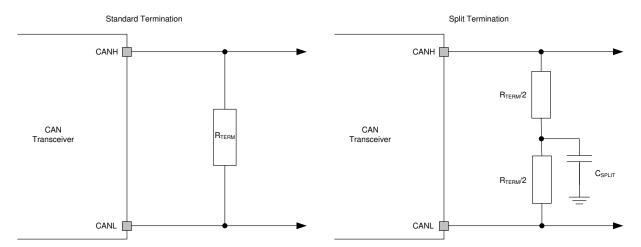


Figure 18. CAN Bus Termination Concepts

9.2.2 Detailed Design Procedures

9.2.2.1 Bus Loading, Length and Number of Nodes

A typical CAN application may have a maximum bus length of 40 meters and maximum stub length of 0.3 m. However, with careful design, users can have longer cables, longer stub lengths, and many more nodes to a bus. A high number of nodes requires a transceiver with high input impedance such as the TCAN1044-Q1.

Many CAN organizations and standards have scaled the use of CAN for applications outside the original ISO 11898-2 standard. They made system level trade off decisions for data rate, cable length, and parasitic loading of the bus. Examples of these CAN systems level specifications are ARINC 825, CANopen, DeviceNet, SAE J2284, SAE J1939, and NMEA 2000.

A CAN network system design is a series of tradeoffs. In the ISO 11898-2:2016 specification the driver differential output is specified with a bus load that can range from 50 Ω to 65 Ω where the differential output must be greater than 1.5 V. The TCAN1044-Q1 family is specified to meet the 1.5-V requirement down to 50 Ω and is specified to meet 1.4-V differential output at 45 Ω bus load. The differential input resistance of the TCAN1044-Q1 is a minimum of 40 k Ω . If 100 TCAN1044-Q1 transceivers are in parallel on a bus, this is equivalent to a 400- Ω differential load in parallel with the nominal 60 Ω bus termination which gives a total bus load of approximately 52 Ω . Therefore, the TCAN1044-Q1 family theoretically supports over 100 transceivers on a single bus segment. However, for CAN network design margin must be given for signal loss across the system and cabling, parasitic loadings, timing, network imbalances, ground offsets and signal integrity thus a practical maximum number of nodes is often lower. Bus length may also be extended beyond 40 meters by careful system design and data rate tradeoffs. For example, CANopen network design guidelines allow the network to be up to 1 km with changes in the termination resistance, cabling, less than 64 nodes and significantly lowered data rate.

This flexibility in CAN network design is one of the key strengths of the various extensions and additional standards that have been built on the original ISO 11898-2 CAN standard. However, when using this flexibility the CAN network system designer must take the responsibility of good network design to ensure robust network operation.



Typical Application (continued)

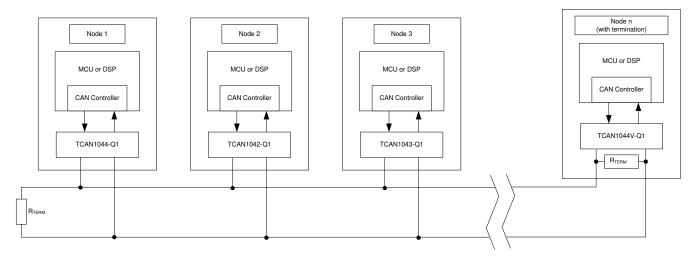
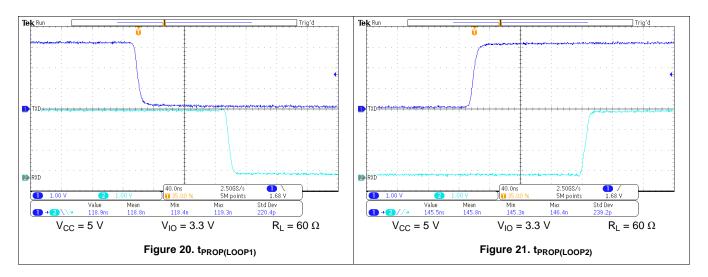


Figure 19. Typical CAN Bus

9.2.3 Application Curves



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9.3 System Examples

The TCAN1044-Q1 CAN transceiver is typically used in applications with a host controller or FPGA that includes the link layer portion of the CAN protocol. A 1.8 V, 2.5 V, or 3.3 V application is shown in Figure 22. The bus termination is shown for illustrative purposes.

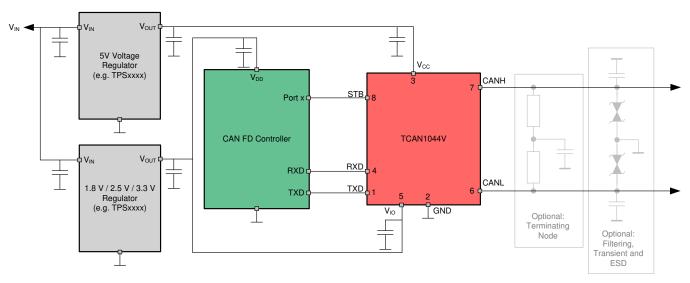


Figure 22. Typical Transceiver Application Using 1.8 V, 2.5 V, 3.3 V IO Connections

10 Power Supply Recommendations

The TCAN1044-Q1 transceiver is designed to operate with a main V_{CC} input voltage supply range between 4.5 V and 5.5 V. The TCAN1044-Q1V implements an IO level shifting supply input, V_{IO} , designed for a range between 1.8 V and 5.5 V. Both supply inputs must be well regulated. A decoupling capacitance, typically 100 nF, should be placed near the CAN transceiver's main V_{CC} supply pin in addition to bypass capacitors. A decoupling capacitor, typically 100 nF, should be placed near the CAN transceiver's V_{IO} supply pin in addition to bypass capacitors.



11 Layout

Robust and reliable CAN node design may require special layout techniques depending on the application and automotive design requirements. Since transient disturbances have high frequency content and a wide bandwidth, high-frequency layout techniques should be applied during PCB design.

11.1 Layout Guidelines

- Place the protection and filtering circuitry close to the bus connector, J1, to prevent transients, ESD, and noise from propagating onto the board. This layout example shows a optional transient voltage suppression (TVS) diode, D1, which may be implemented if the system-level requirements exceed the specified rating of the transceiver. This example also shows optional bus filter capacitors C4 and C5.
- Design the bus protection components in the direction of the signal path. Do not force the transient current to divert from the signal path to reach the protection device.
- Use V_{CC} and GND planes to provide low inductance. Note that high frequency current follows the path of least impedance and not the path of least resistance.
- Decoupling capacitors should be placed as close as possible to the supply pins V_{CC} and V_{IO} of transceiver.
- Use at least two vias for V_{CC} and ground connections of decoupling capacitors and protection devices to minimize trace and via inductance.
- This layout example shows how split termination could be implemented on the CAN node. The termination is split into two resistors, R6 and R7, with the center or split tap of the termination connected to ground via capacitor C3. Split termination provides common mode filtering for the bus. See CAN Termination, CAN Bus Short Circuit Current Limiting, and Equation 2 for information on termination concepts and power ratings needed for the termination resistor(s).
- To limit current of digital lines series resistors may be used. Examples are R2, R3 and R4.
- Pin 1 is shown for the TXD input of the device with R1 as an optional pull-up resistor. If an open drain host controller is used this is mandatory to ensure the bit timing into the device is met.
- Pin 8 is shown with R4 assuming the mode pin STB, is used. If the device is used in normal mode only, R4 is not needed and the pads of C4 could be used for the pull down resistor R5 to GND.

11.2 Layout Example

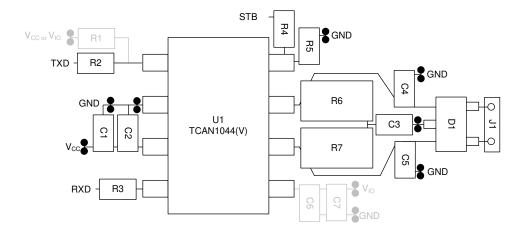


Figure 23. Layout Example



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

Table 8. Related Links

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TCAN1044-Q1	Click here	Click here	Click here	Click here	Click here
TCAN1044V-Q1	Click here	Click here	Click here	Click here	Click here

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





19-May-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
PTCAN1044DDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	TBD	Call TI	Call TI	-40 to 125		Samples
PTCAN1044DRBRQ1	ACTIVE	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125	P1044	Samples
PTCAN1044VDRBRQ1	ACTIVE	SON	DRB	8	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	P1044V	Samples
TCAN1044DRBRQ1	PREVIEW	SON	DRB	8	3000	TBD	Call TI	Call TI	-40 to 125		
TCAN1044VDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	26SF	Samples
TCAN1044VDRQ1	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	-40 to 125	1044V	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

19-May-2020

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

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OTHER QUALIFIED VERSIONS OF TCAN1044V-Q1:

Catalog: TCAN1044V

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TCAN1044VDDFRQ1	SOT- 23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TCAN1044VDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TCAN1044VDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
TCAN1044VDRQ1	SOIC	D	8	2500	367.0	367.0	35.0



PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



PLASTIC SMALL OUTLINE



NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.





SMALL OUTLINE INTEGRATED CIRCUIT



NOTES:

- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

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